



BRAINWARE UNIVERSITY

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Brainware University
398, Ramkrishnapur Road, Barasat
Kolkata, West Bengal-700125

Term End Examination 2025-2026

**Programme – B.Tech.(CSE)-2024/B.Tech.(CSE)-AIR-2024/B.Tech.(CSE)-2025/B.Tech.
(CSE)-AIR-2025**

Course Name – Basic Electrical and Electronics Engineering

Course Code - BES00002

(Semester II)

Full Marks : 60

Time : 2:30 Hours

[The figure in the margin indicates full marks. Candidates are required to give their answers in their own words as far as practicable.]

Group-A

(Multiple Choice Type Question)

1 x 15=15

1. Choose the correct alternative from the following :

- (i) Select the unit of reactive power;

a) VA	b) Watt
c) VAR	d) Ohm
- (ii) Select the Unit of inductive reactance;

a) Henry	b) mili-Henry
c) Weber	d) Ohm
- (iii) Choose from the following the law on which KCL is based:

a) Law of conservation of charge	b) Law of conservation of energy
c) Law of conservation of mass	d) None of these
- (iv) Choose the rating of transformer;

a) KVA	b) KW
c) HP	d) KVAR
- (v) Predict the right choice. Laminating the stator core of a three-phase induction motor lowers the

a) Eddy current loss	b) Hysteresis loss
c) Both of these	d) Weight of the stator
- (vi) Select the no-load speed of the following DC motor that will be highest.

a) Shunt motor	b) Series motor
c) Cumulative compound motor	d) Differentially compound motor
- (vii) A sine wave has a frequency of 50 Hz. Indicate the value of angular frequency;

a) 31.4 rad/s	b) 314 rad/s
c) 3.14 rad/s	d) None of these
- (viii) Select the unit of electrical charge from the following:

a) Coulomb	b) Joule
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- c) Volt
d) Watt
- (ix) Select the principle behind electromagnetic induction-
a) Faraday's Law
b) Coulomb's Law
c) Ohm's Law
d) Kirchhoff's Law
- (x) Indicate, Which of the following expressions doesn't represent the correct formula for Drift current density.
a) $J = \sigma E$
b) $J = qn\mu E$
c) $J = \mu E$
d) None
- (xi) Select the cut-in voltage of a Si diode :
a) 0.3 V
b) 0.7 V
c) 0.3 mV
d) 0.7 mV
- (xii) Select the band gap of a Silicon
a) 1.1 eV
b) 2.1 eV
c) 0.72 eV
d) 0.82 eV
- (xiii) Identify the doping level associated with Zener breakdown in a Zener diode.
a) Lowest
b) Moderate
c) High
d) Low
- (xiv) State the ripple factor for a half-wave rectifier.
a) 2
b) 1.21
c) 0.482
d) 0.877
- (xv) State full form of PIV
a) Peak Voltage
b) Peak Inverse Voltage
c) Peak Inverse Volume
d) None of these

Group-B

(Short Answer Type Questions)

3 x 5=15

2. Explain the construction of PNP and NPN transistor with diagram. (3)
3. Compare a half-wave and a full-wave rectifier. (3)
4. Explain the need for a starter in a DC motor. (3)
5. Explain superposition theorem. (3)
6. Distinguish between Electric and Magnetic circuits. (3)

OR

- Explain the phenomenon of drift and diffusion of current carriers in a semiconductor (3)

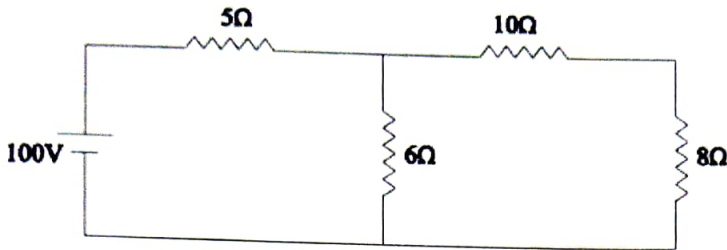
Group-C

(Long Answer Type Questions)

5 x 6=30

7. Describe different types of losses occurring in a transformer. Define the process to reduce eddy current loss (5)
8. Calculate the current through 8 ohm resistance using thevenin's theorem. (5)

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9. Define node, junction, loop and mesh of a circuit. (5)
 10. Explain the Drift current and Diffusion current in a semiconductor device. (5)
 11. Compare in between BJT and FET. (5)
 12. Analyze the V-I characteristics of a PN junction diode under forward and reverse bias and justify the deviation from ideal behavior. (5)
- OR**
- Compare Zener and avalanche breakdown mechanisms with respect to doping concentration and electric field intensity. (5)

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